

US1A-DM THRU US1M-DM

SURFACE MOUNT ULTRAFAST RECOVERY RECTIFIER

Reverse Voltage – 50 to 1000 V

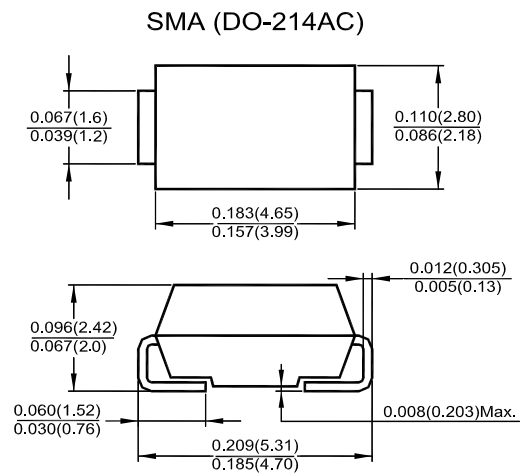
Forward Current – 1 A

Features

- For surface mount applications
- Low profile package
- Built-in strain relief
- Easy pick and place
- Ultrafast recovery times for high efficiency
- Plastic package has Underwriters Laboratories Flammability Classification 94V-0

Mechanical Data

- **Case:** SMA (DO-214AC) molded plastic
- **Terminals:** Solder plated, solderable per MIL-STD-750, method 2026 guaranteed
- **Polarity:** Color band denotes cathode end



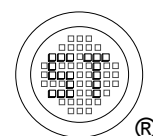
Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	US1A	US1B	US1D	US1G	US1J	US1K	US1M	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at $T_L = 100\text{ }^\circ\text{C}$	$I_{F(AV)}$	1							A
Peak Forward Surge Current 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	30							A
Maximum Forward Voltage at 1 A	V_F	1		1.4	1.7			V	
Maximum DC Reverse Current $T_A = 25\text{ }^\circ\text{C}$ at Rated DC Blocking Voltage $T_A = 100\text{ }^\circ\text{C}$	I_R	5							μA
Typical Junction Capacitance at 4 V, 1 MHz	C_J	17							pF
Maximum Reverse Recovery Time at $I_F = 0.5\text{ A}$, $I_R = 1\text{ A}$, $I_{rr} = 0.25\text{ A}$	t_{rr}	50				75			ns
Typical Thermal Resistance ¹⁾	$R_{\theta JA}$	50							$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{Stg}	- 55 to + 150							$^\circ\text{C}$

¹⁾ Mounted on P.C.B. with 0.2 X 0.2" (5 X 5 mm) copper pad areas.



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